

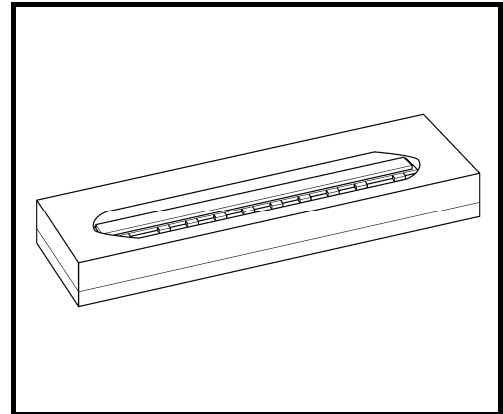
TOSHIBA CCD Image Sensor CCD (charge coupled device)

TCD1254GFG

The **TCD1254GFG** is a high sensitive and low dark current 2500-elements linear image sensor. This device consists of sensitivity CCD chip. The TCD1254GFG has electronic shutter function (ICG). Electronic shutter function can keep always output voltage constant that vary with intensity of lights.

Features

- Number of Image Sensing Elements: 2500 elements
- Image Sensing Element Size: 5.25 μm \times 64 μm
- Photo Sensing Region: High sensitive and low dark current pn photodiode
- Internal Circuit: CCD Drive Circuit
- Power Supply: Only 3.0V Drive (MIN.)
- Function: Electronics Shutter, Sample and Hold Circuit
- Package: 16 pin GLCC Package



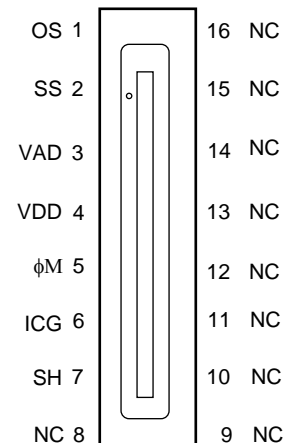
Weight: 0.47 g (typ.)

Maximum Ratings (Note1)

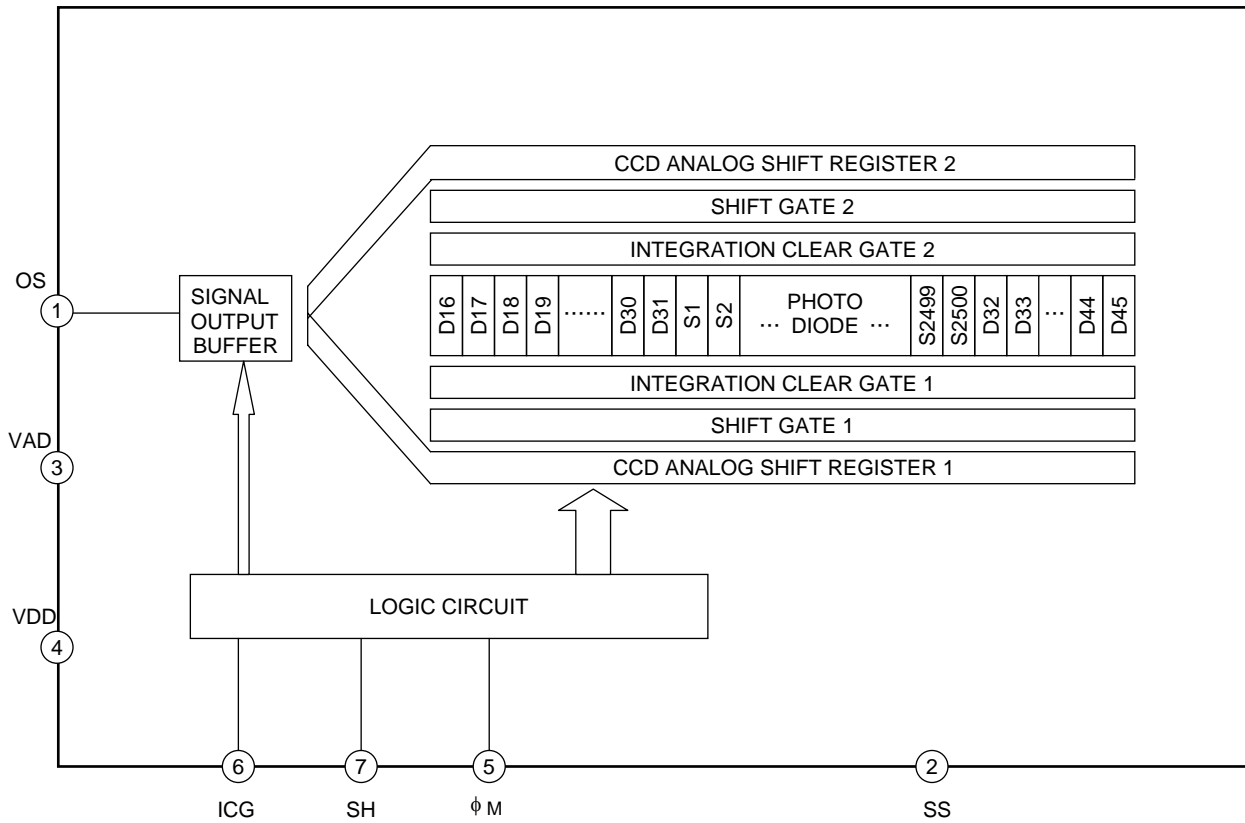
| Characteristic | Symbol | Rating | Unit |
|----------------------------|--------------|----------|--------------------|
| Master clock pulse voltage | $V_{\phi M}$ | -0.3~7.0 | V |
| Shift pulse voltage | V_{SH} | | |
| ICG pulse voltage | V_{ICG} | | |
| Digital power supply | V_{DD} | | |
| Analog Power Supply | V_{AD} | | |
| Operating temperature | T_{opr} | -25~60 | $^{\circ}\text{C}$ |
| Storage temperature | T_{stg} | -40~85 | $^{\circ}\text{C}$ |

Note 1: All voltage is with respect to SS terminals (ground).

Pin Connections (top view)



Block Diagram



Pin Names

| Pin No. | Symbol | Name | Pin No. | Symbol | Name |
|---------|----------|------------------------|---------|--------|----------------|
| 1 | OS | Output signal | 16 | NC | Non Connection |
| 2 | SS | Ground | 15 | NC | Non Connection |
| 3 | VAD | Power (Analog) | 14 | NC | Non Connection |
| 4 | VDD | Power (Digital) | 13 | NC | Non Connection |
| 5 | ϕ M | Master clock | 12 | NC | Non Connection |
| 6 | ICG | Integration clear gate | 11 | NC | Non Connection |
| 7 | SH | Shift gate | 10 | NC | Non Connection |
| 8 | NC | Non connection | 9 | NC | Non Connection |

Optical/Electrical Characteristics

(Ta = 25°C, V_φ = 4.0V (pulse), f_{φM} = 2.0 MHz (Data rate=1MHz), Tint(Integration time) =10ms, Load resistance = 100 kΩ, VAD = VDD = 4.0V, Light source = Daylight fluorescent lamp)

| Characteristics | Symbol | Min | Typ. | Max | Unit | Note |
|---------------------------------------|------------------|-----|------|-----|--------|-----------|
| Sensitivity | R | 72 | 103 | — | V/lx·s | (Note2) |
| Photo response non uniformity | PRNU | — | — | 10 | % | (Note3) |
| Register imbalance | RI | — | 1.5 | 3 | % | (Note4) |
| Saturation output voltage | V _{SAT} | 0.7 | 1.0 | — | V | (Note5) |
| Saturation exposure | SE | — | 0.01 | — | lx·s | (Note6) |
| Dark signal voltage | V _{MDK} | — | 2.5 | 15 | mV | (Note7) |
| DC power dissipation | PD | — | 24 | 60 | mW | |
| Total transfer efficiency | TTE | 92 | 95 | — | % | (Note 8) |
| Low voltage total transfer efficiency | LVTTE | 92 | 95 | — | % | (Note 9) |
| | | 83 | 88 | — | % | (Note 10) |
| Output impedance | Z _O | — | 0.5 | 1.0 | κΩ | |
| DC output voltage | V _{OS} | 1.5 | 2.3 | 3.0 | V | (Note 11) |
| Dynamic range | DR | — | 400 | — | — | (Note 12) |

Note 2: Sensitivity is defined for signal outputs when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

Note 3: PRNU is defined for a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

$$PRNU = \frac{\Delta X}{\bar{X}} \times 100(\%)$$

Where \bar{X} is average of total signal output and ΔX is the maximum deviation from \bar{X} . The amount of incident light is 1/2·SE.

Note 4: Register imbalance is defined as follows.

$$RI = \frac{\Delta Y}{\bar{X}} \times 100(\%)$$

Where \bar{X} is average of total signal output.

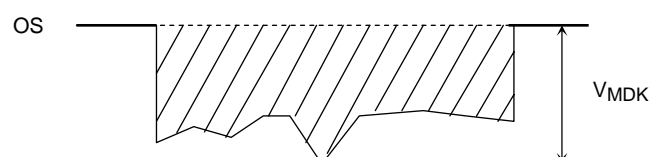
ΔY : | average of odd signal output – average of even signal output |

Note 5: V_{SAT} is defined as minimum saturation output of all effective pixels.

Note 6: Definition of SE

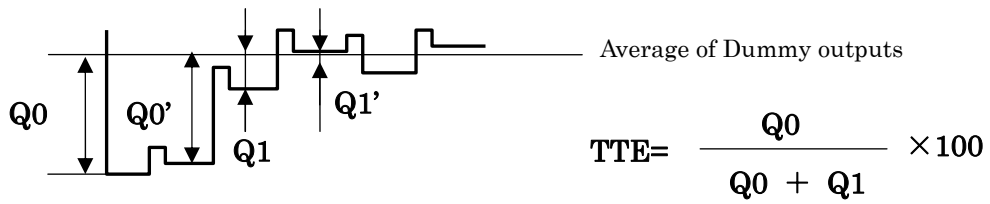
$$SE = \frac{V_{SAT}}{R} \text{ (lx·s)}$$

Note 7: V_{MDK} is defined as maximum dark signal voltage of all effective pixels.



Note 8: Total transfer efficiency is defined as follow.

* Q0=500mV



$$TTE = \frac{Q0}{Q0 + Q1} \times 100$$

Use Q0' and Q1' instead of Q0 and Q1 if Q1' > Q1.

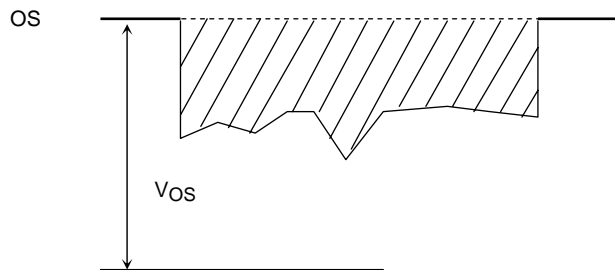
Note 9: Definition of Low voltage total transfer efficiency is same as Note 8 without power supply and Q0.

* 4V ≤ Power supply ≤ 5 V
 * Q0 = 50mV

Note 10: Definition is same as Note 9 without power supply as follows.

* 3V ≤ Power supply < 4 V

Note 11: DC signal output voltage is defined as follows.



Note 12: Definition of DR

$$DR = \frac{VSAT}{VMDK}$$

VMDK is proportional to Tint (Integration time), so, the shorter Tint condition makes wider DR.

Operating Condition

| Characteristics | | Symbol | Min | Typ. | Max | Unit | |
|--------------------------------|-----------|--------------|-----|------|------|------|-----------|
| Master clock pulse voltage | "H" Level | $V_{\phi M}$ | 3.0 | 4.0 | 5.0 | V | (Note 13) |
| | "L" Level | | 0 | 0 | 0.44 | | |
| Shift pulse voltage | "H" Level | V_{SH} | 3.0 | 4.0 | 5.0 | V | (Note 13) |
| | "L" Level | | 0 | 0 | 0.44 | | |
| ICG pulse voltage | "H" Level | V_{ICG} | 3.0 | 4.0 | 5.0 | V | (Note 13) |
| | "L" Level | | 0 | 0 | 0.44 | | |
| Power supply voltage (Digital) | | V_{DD} | 3.0 | 4.0 | 5.0 | V | (Note 14) |
| Power supply voltage (Analog) | | V_{AD} | 3.0 | 4.0 | 5.0 | V | (Note 14) |

Note 13 "H" level of maximum pulse voltage = $V_{DD} \geq V_{DD} - 0.5V$ = "H" level of minimum pulse voltage.

Note 14 $V_{AD} = V_{DD}$

Clock Characteristics ($T_a = 25^\circ\text{C}$) ($3.0V \leq V_{AD} = V_{DD} \leq 5.0V$)

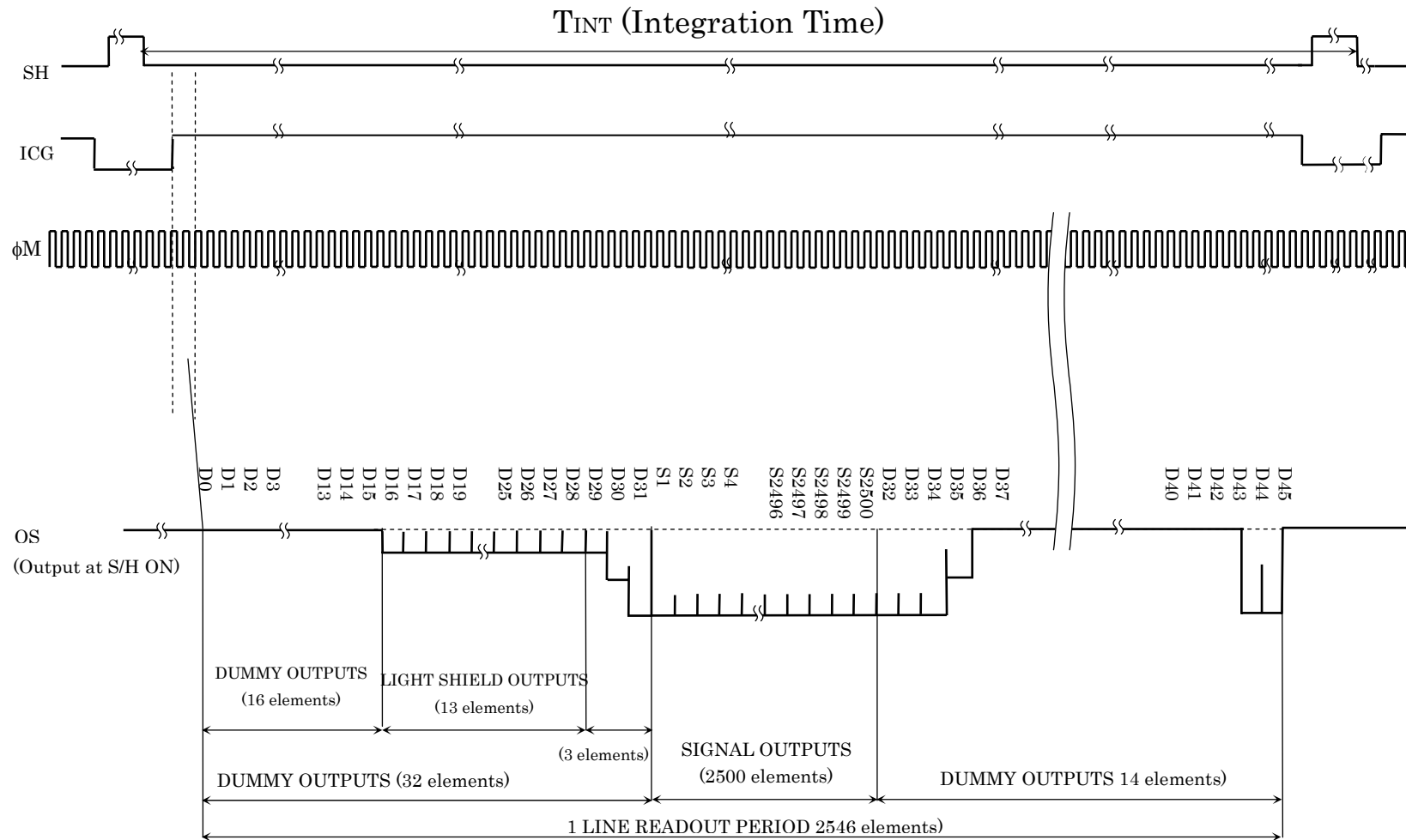
| Characteristics | Symbol | Min | Typ. | Max | Unit |
|--------------------------|--------------|-----|------|-----|------|
| Master clock frequency | $f_{\phi M}$ | 0.4 | 2 | 4 | MHz |
| Data Rate | f_{DATA} | 0.2 | 1 | 2 | MHz |
| Master clock capacitance | $C_{\phi M}$ | — | 10 | — | pF |
| Shift pulse capacitance | C_{SH} | — | 200 | — | pF |
| ICG Pulse capacitance | C_{ICG} | — | 50 | — | pF |

Optical/Electrical characteristics of page 3 are defined under the condition of 1MHz data rate.

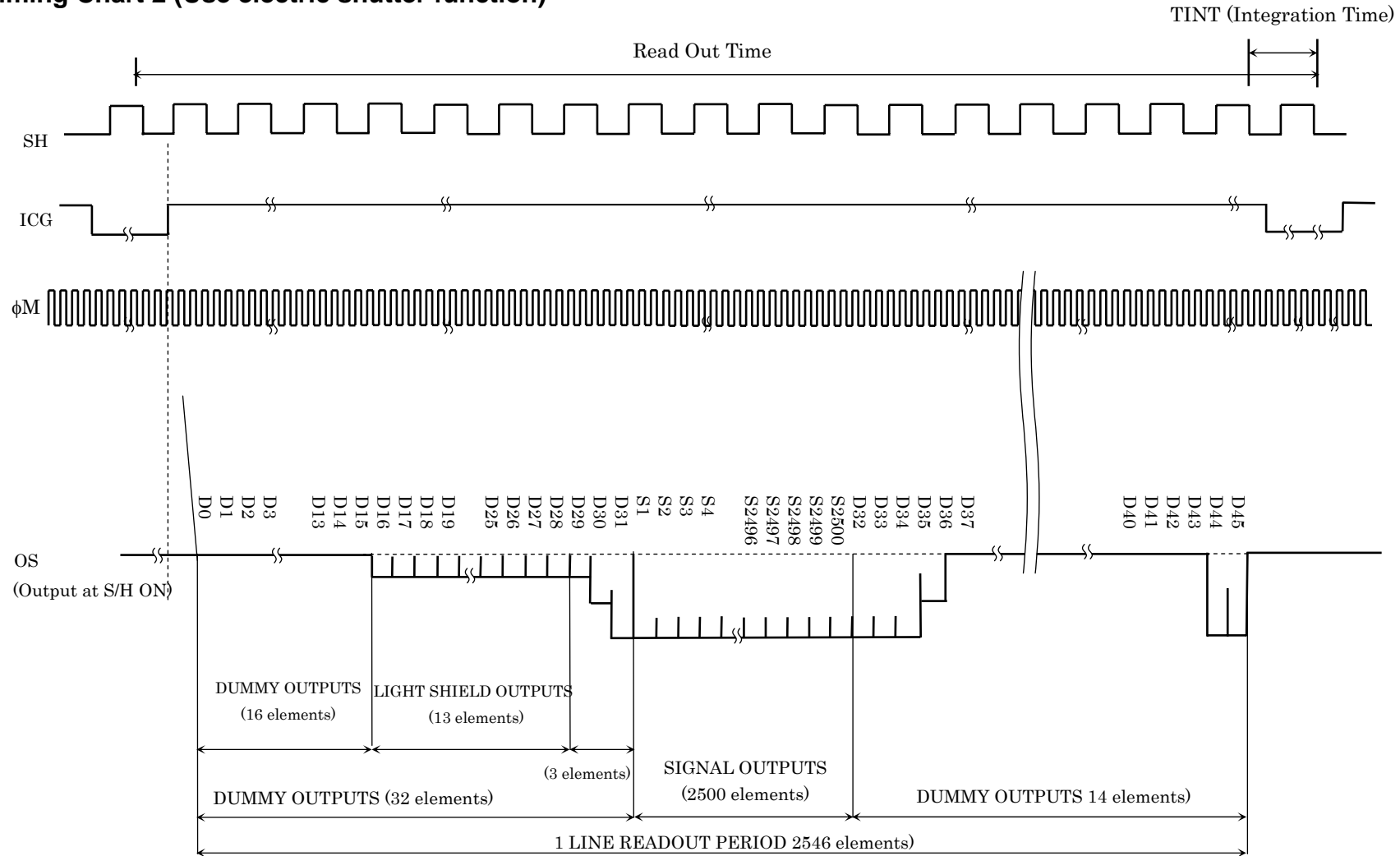
Power- On characteristics

CCD sensor has the characteristics that a correct output signal will be appeared after power supply reached to regular voltage. It is required to 10 cycles of read out time at least after power supply reached to regular voltage. This characteristics should be considered, when circuit designs.

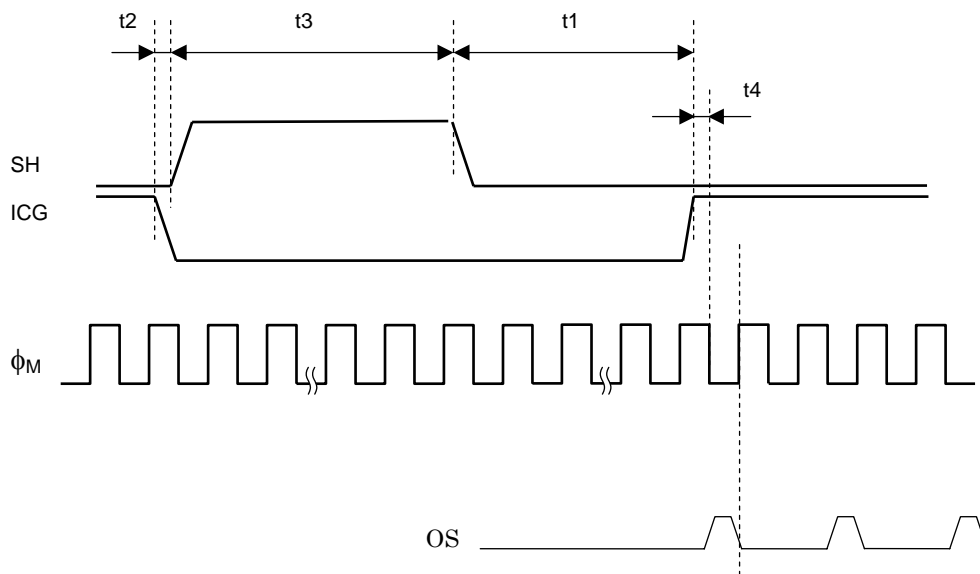
Timing Chart 1



Timing Chart 2 (Use electric shutter function)



Timing Requirements

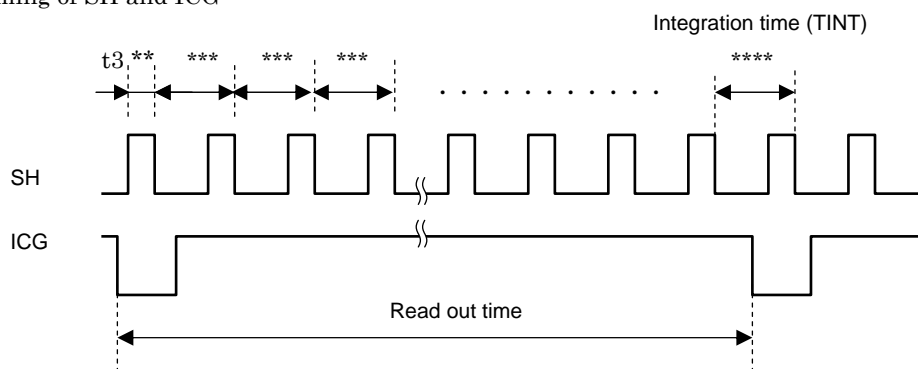


| Characteristics | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------|------|------|------|------|
| ICG pulse delay | t_1 | 1000 | 5000 | — | ns |
| Pulse timing of ICG and SH | t_2 | 100 | 500 | 1000 | ns |
| Shift pulse width | t_3 | 1000 | — | — | ns |
| Pulse timing of ICG and ϕ_M | t_4 | 0 | 20 | * | ns |

* : To keep ϕ_M “High” level when ICG switch from “Low” to “High” level.

Use electronic shutter

Pulse timing of SH and ICG



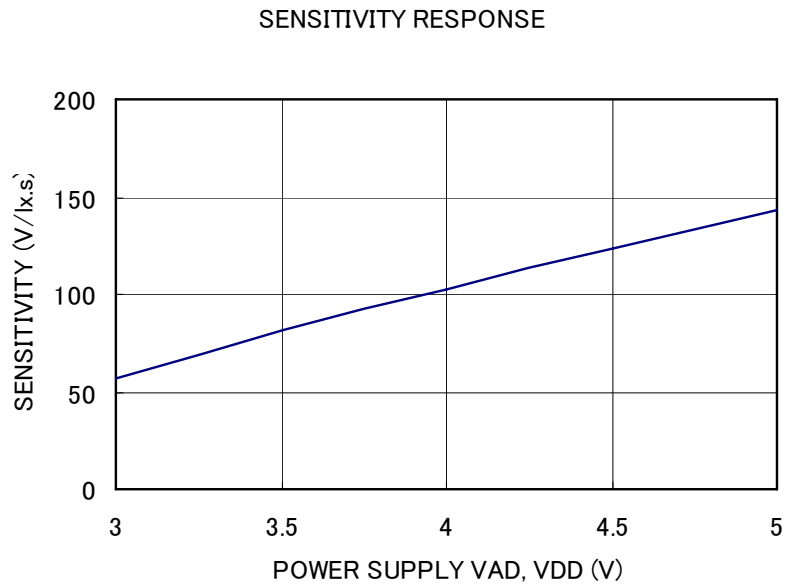
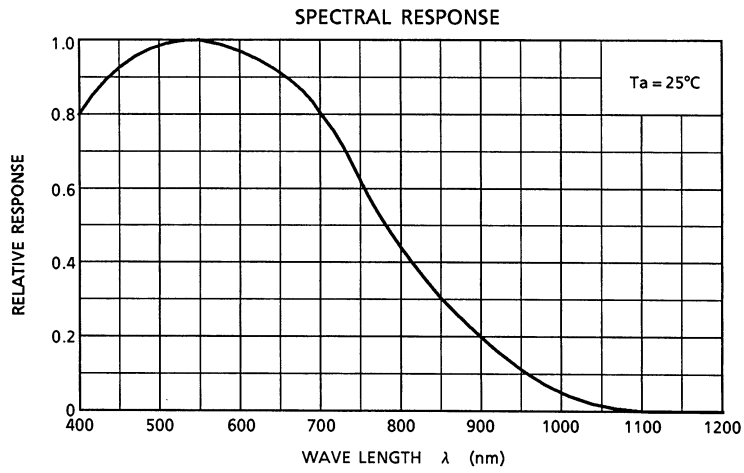
** : Each SH high pulse have to keep always the same value with “ t_3 ”. ($t_3 \geq 1000\text{ns}$ (Min.))

*** : SH pulse cycle have to keep the same cycle (SH cycle period $\geq 10 \mu\text{s}$) except TINT period.

**** : TINT $\geq 10 \mu\text{s}$ (Min.)

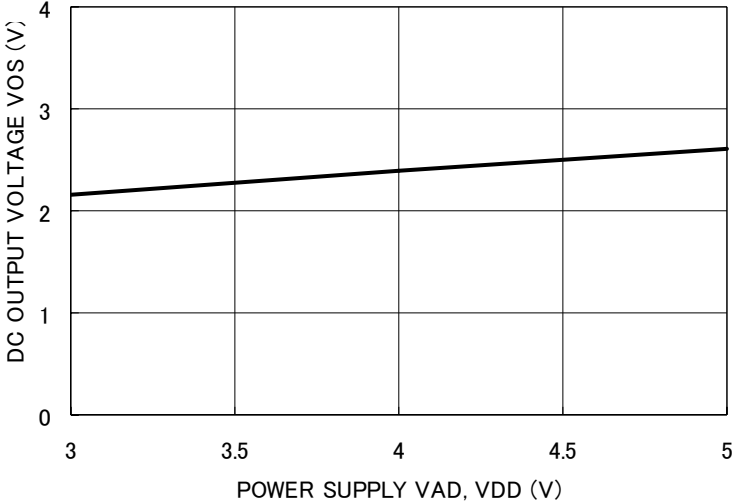
Note : The illumination of light source must be used with less than 1000 times based on 10ms TINT.

Typical performance curves

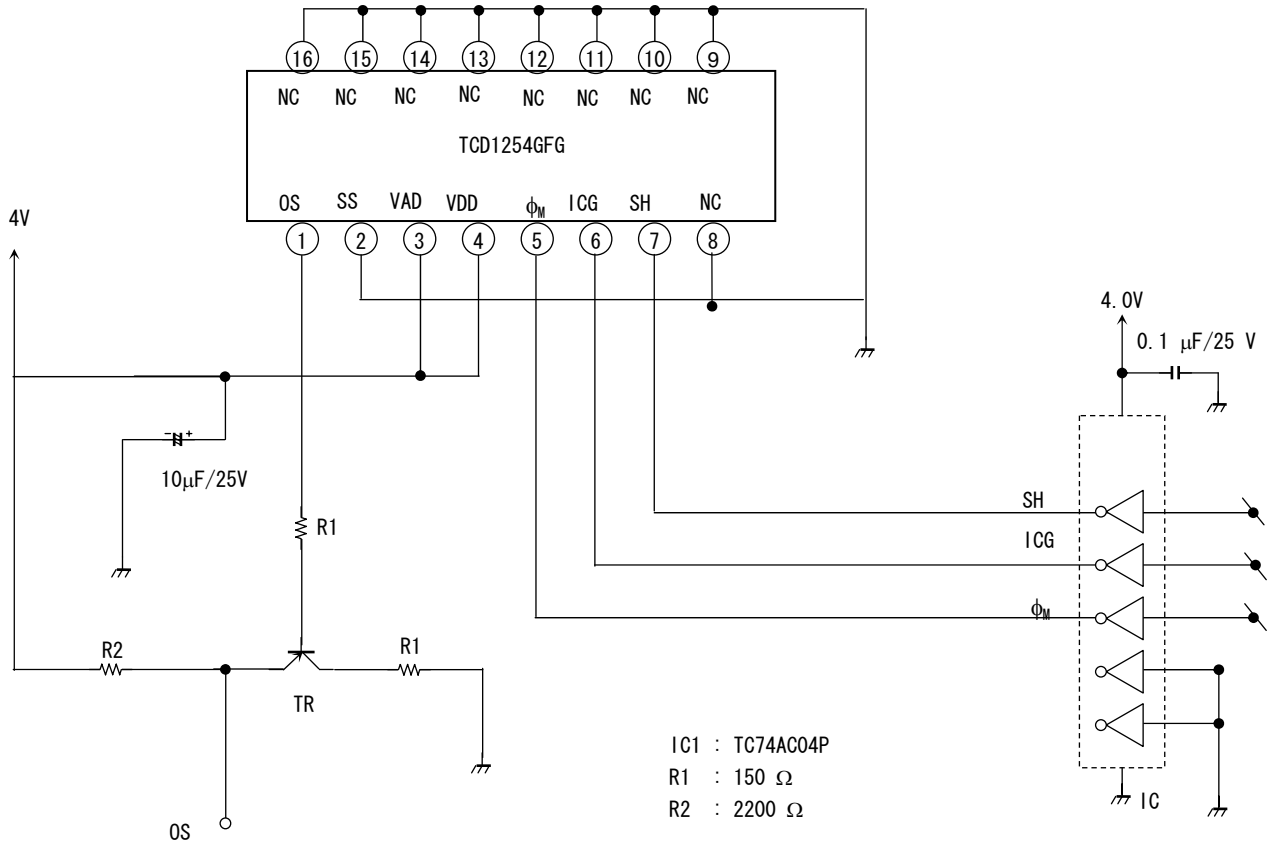


Typical performance curves

DC OUTPUT VOLTAGE -
POWER SUPPLY VOLTAGE



Typical Drive Circuit



Caution**1. Electrostatic Breakdown**

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handling the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

- a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
- b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
- c. Ground the tools such as soldering iron, cutting pliers, tweezers or pincer.

It is not necessarily required to execute all precaution items for static electricity.

It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

- d. When the product is handed, please use tweezers to avoid the damage of CCD image sensor. Recommended tweezers is P-815 (HOZAN) or equivalent.
- e. Ionized air is recommended for discharge when handling CCD image sensors.

2. Incident Light

CCD sensor is sensitive to infrared light. Note that infrared light component degrades resolution and PRNU of CCD sensor.

3. Ultrasonic Cleaning

Ultrasonic cleaning should not be used with such hermetically-sealed ceramic package as CCD because the bonding wires can become disconnected due to resonance during the cleaning process.

4. Window Glass Protective Tape

The window glass protective tape is manufactured from materials in which static charges tend to build up. When removing the tape from CCD sensor after solder mounting, install an ionizer to prevent the tape from being charged with static electricity.

When the tape is removed, adhesives will remain in the glass surface. Since these adhesives appear as black or white flaws on the image, please wipe the window glass surface with the cloth into which the organic solvent was infiltrated. Then please attach CCD to a product.

Do not reuse the tape.

5. Cleaning Method of the Window Glass Surface

Wiping Cloth

- a. Use soft cloth with a fine mesh.
- b. The wiping cloth must not cause dust from itself.
- c. Use a clean wiping cloth necessarily.

Recommended wiping cloth is as follow;

- MK cloth (Toray Industries)

Cleaner

Recommended cleaning liquid of window glass are as follow;

- EE-3310 (Olympus)

When using solvents, such as alcohol, unavoidably, it is cautious of the next.

- a. A clean thing with quick-drying.
- b. After liquid dries, there needs to be no residual substance.
- c. A thing safe for a human body.

And, please observe the use term of a solvent and use the storage container of a solvent to be clean.

Be cautious of fire enough.

Way of Cleaning

First, the surface of window glass is wiped with the wiping cloth into which the cleaner was infiltrated.

Please wipe down the surface of window glass at least 2 times or more.

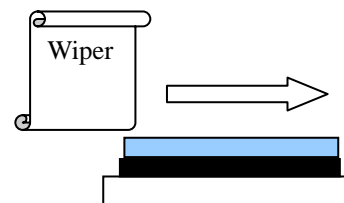
Next, the surface of window glass wipes with the dry wiping cloth. Please wipe down the surface of window glass at least 3 times or more.

Finally, blow cleaning is performed by dry N2 filtered.

If operator wipes the surface of the window glass with the above-mentioned process and dirt still remains, Toshiba recommends repeating the clean operation from the beginning.

Be cautious of the next thing.

- a. Don't infiltrate the cleaner too much.
- b. A wiping portion is performed into the optical range and don't touch the edge of window glass.
- c. Be sure to wipe in a long direction and the same direction.
- d. A wiping cloth always uses an unused portion.



The standard reflow condition for GLCC (Surface Mount device, Pb-Free)

1. Storage precautions

- 1) Do not drop or toss device packaging. The laminated aluminum material in it can be rendered ineffective by rough handling.
- 2) Ensure packaging materials are stored in a 30°C90%RH environment and do not store at the low temperature to prevent dew condensation. Use devices within 12 months; do not store them longer than that.
- 3) If the 30% humidity indicator is pink when the packaging is opened, bake the devices at 125°C for 24 hours to remove any moisture present. Devices should also be baked, whether still packed or not, if the effective usage period of the indicator has expires.
- 4) Perform destructive prevention of the devices by static electricity in case of implementation of baking processing.
- 5) After opening the moisture-proof packing, store the products in the environment under 30°C, and below 60%RH, and use them within 5 days.
If the effective usage period passed after opening the moisture-proof packing, baking should be done before use at 125°C for 24 hours.
- 6) CCD surface mount products may have a haze on the inside of glass, so be careful about folling.
Even if the haze arises inside of glass, when it is not on the pixel eria, there is no problem in quality.

2. Mounting conditions using reflow

- 1) Mounting method : (a) Hot air reflows.
(b) Infrared ray reflow
- 2) Preheating condition : 150~180°C, 60~120 seconds
- 3) Reflow condition : (a) maximum 240°C
(b) over 230°C, within 30~50 seconds
- 4) Heating times : only 1 time
- 5) Caution : This product does not support a Re-flow with Pb-Sn solder. Pb-free solder should be used to Re-flow with Fig1's profile.

* The temperature profile is specified in terms of the temperature of top surface of the device. This temperature profile shows maximum guaranteed device temperature. Please set up the optimum temperature profile conditions within the Fig.1 profile.

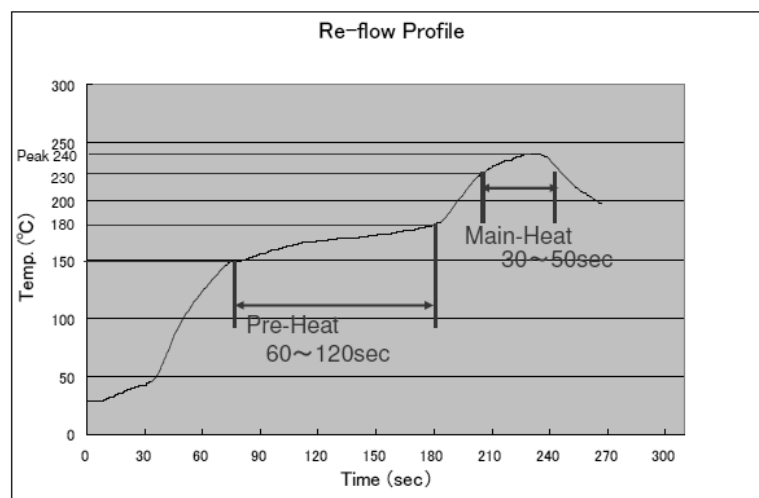


Fig.1 Example of recommended temperature profile for reflows

In addition, in case of the repair work accompanied by IC removal, since the degree of parallel may be spoiled with the left solder, please do not carry out.

3. Mounting

- 1) In the case of solder mounting, the devices should be mounted with the window glass protective tape in order to avoid dust or dirt included in reflow machine.
- 2) The window glass protective tape is manufactured from materials in which static charges tend to build up. When removing the tape from CCD sensor after solder mounting, install an ionizer to prevent the tape from being charged with static electricity.
- 3) When the tape is removed, adhesives will remain in the glass surface. Since these adhesives appear as black or white flaws on the image, please wipe the window glass surface with the cloth into which the organic solvent was infiltrated. Then please attach CCD to a product.
- 4) Do not reuse the window glass protective tape.
- 5) The parts of glass seal area have possibility to be became clouded by reflow process, however, there is no problem in quality..

4. Foot Pattern on the PCB

We recommend Fig 2's foot pattern for your PCB (Printed circuit Board).

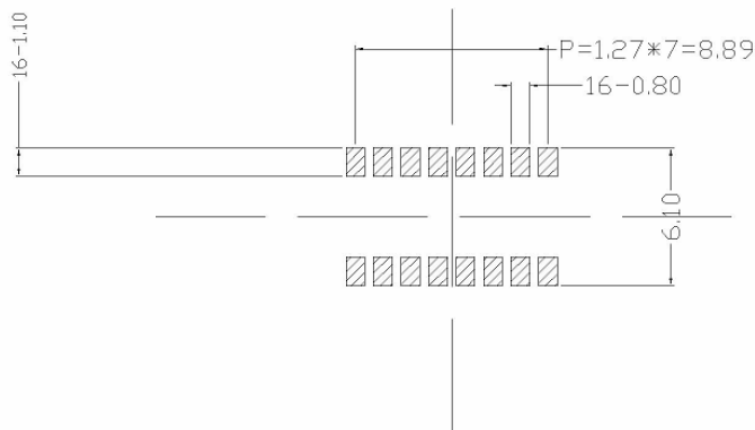


Fig.2

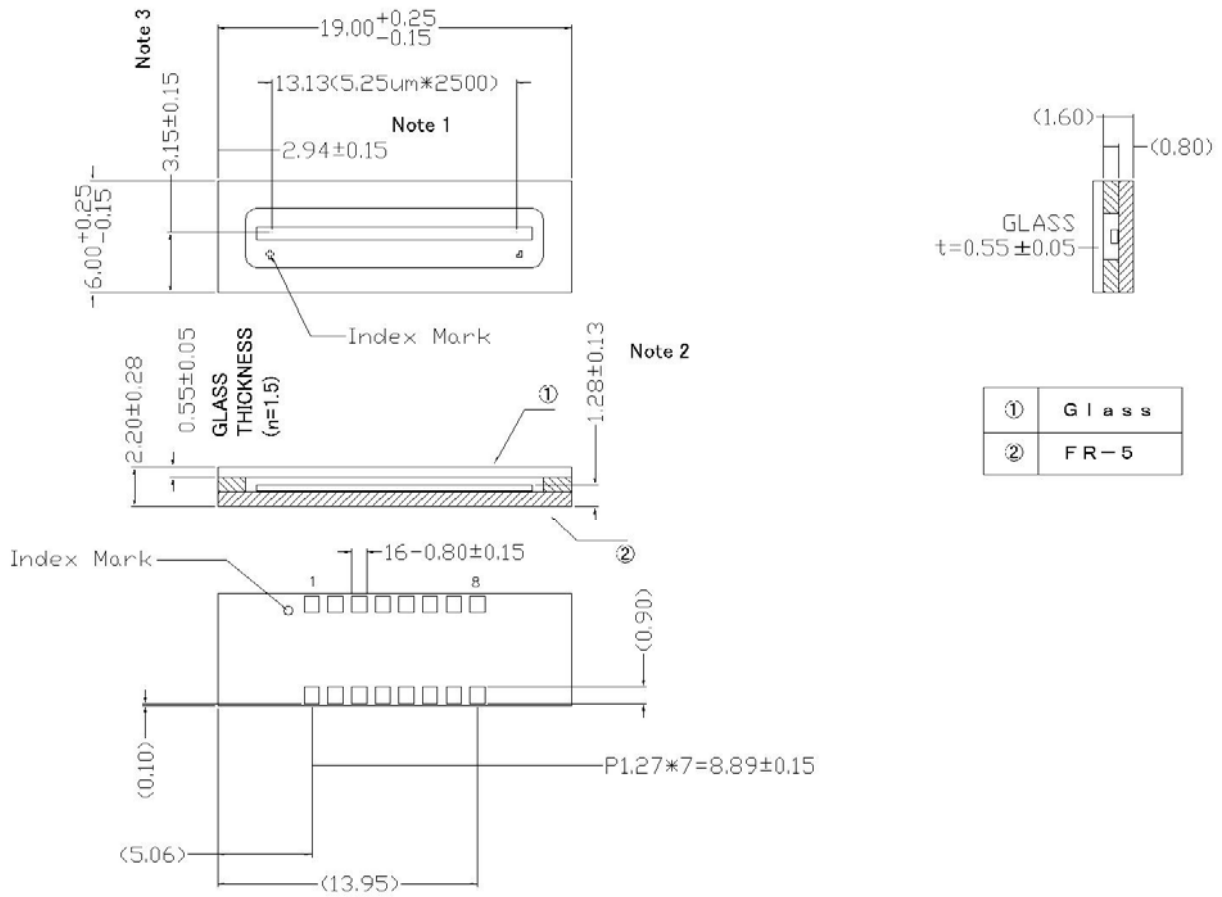
5. Mask for Solder Paste Application

We recommend metal mask that have the following thickness.

- a thickness of 0.1mm.

And, we recommend that the size of the pattern of the metal mask is 100% of recommended foot pattern at fig. 2.

Package Dimensions



Note 1: Sensor pixel (S1) to edge of package
 Note 2: Top of chip to bottom of package
 Note 3: Chip center to edge of package

| Revision | Date | Description | Note |
|----------|------------|------------------------------------------------------------------|------|
| 1.0 | 2008-6-23 | New | - |
| 2.0 | 2008-12-25 | Modified: Typical performance curve Added: Caution of storage | - |
| 3.0 | 2009-01-15 | Deleted: Cautions of soft tray | - |

RESTRICTIONS ON PRODUCT USE

060925EBA_R6

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